TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74AC257P, TC74AC257F, TC74AC257FN TC74AC258P, TC74AC258F, TC74AC258FN

TC74AC257P/F/FN 2 – CHANNEL MULTIPLEXER (3 – STATE) TC74AC258P/F/FN 2 – CHANNEL MULTIPLEXER (3 – STATE, INVERTING)

The TC74AC257 and TC74AC258 are advanced high speed CMOS MULTIPLEXERs fabricated with silicon gate and double-layer metal wiring  $C^2MOS$  technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Each is composed of four independent 2-channel multiplexers with common SELECT and  $\overline{OUTPUT}$  ENABLE ( $\overline{OE}$ ).

The TC74AC257 is a non-inverting multiplexer, while the TC74AC258 is an inverting.

If  $\overline{OE}$  is set low, the outputs are held in a high-impedance state. When SELECT is set low, "A" data inputs are enabled. Conversely, when SELECT is high, "B" data inputs are enabled.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

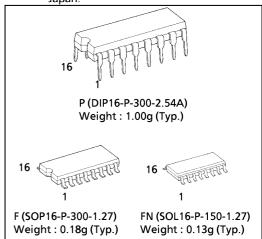
#### FEATURES:

- High Speed······ $t_{pd}$  = 3.6ns(typ.) at  $V_{CC}$  = 5V
- Low Power Dissipation ············· $I_{CC} = 8\mu A(Max.)$  at Ta = 25°C
- High Noise Immunity  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Symmetrical Output Impedance...  $|I_{OH}| = I_{OL} = 24$ mA (Min.) Capability of driving  $50\Omega$

tansmission lines.

- Balanced Propagation Delays ····· t<sub>pLH</sub> ≃ t<sub>pHL</sub>
- Wide Operating Voltage Range ···· V<sub>CC</sub> (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74F257/258

(Note) The JEDEC SOP (FN) is not available in Japan.

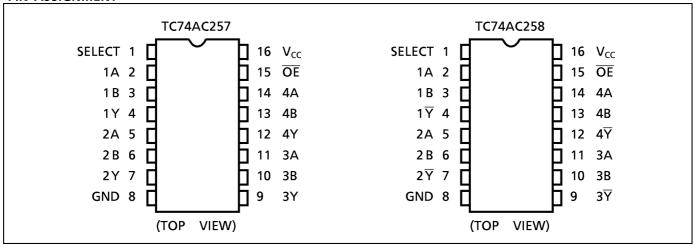


#### TRUTH TABLE

	INPU	ITS	OUTPUTS			
ŌĒ	SELECT	Α	В	Y (257)	<b>∀</b> (258)	
Н	Х	Χ	Х	Z	Z	
L	L	L	Х	L	Н	
L	L	Н	Х	Н	L	
L	Н	Х	L	L	Н	
L	Н	Х	Н	Н	L	

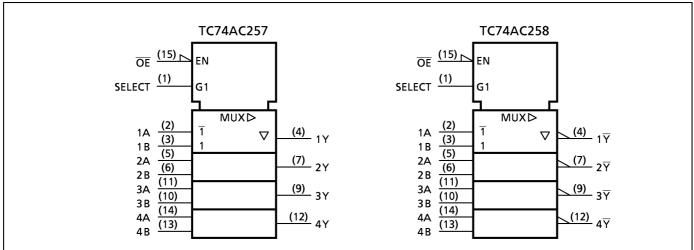
X: Don't Care Z: High Impedance

#### **PIN ASSIGNMENT**

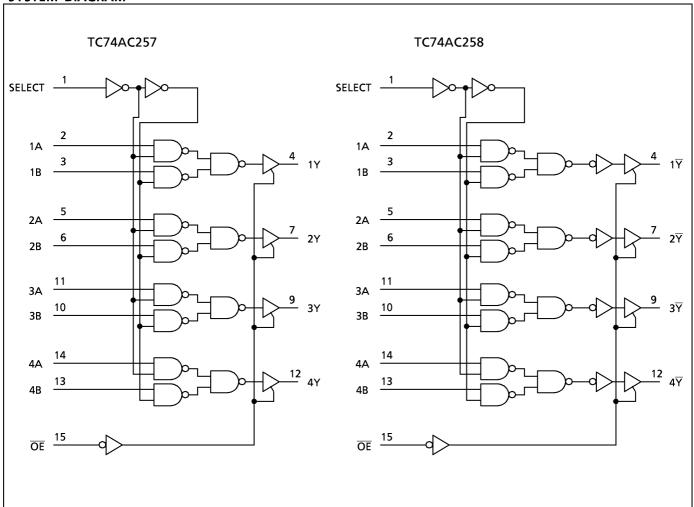


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#### **IEC LOGIC SYMBOL**



#### **SYSTEM DIAGRAM**



## **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V <sub>cc</sub>	-0.5~7.0	V
DC Input Voltage	V <sub>IN</sub>	-0.5~V <sub>CC</sub> +0.5	٧
DC Output Voltage	V <sub>OUT</sub>	−0.5~V <sub>CC</sub> + 0.5	V
Input Diode Current	I <sub>IK</sub>	± 20	mA
Output Diode Current	I <sub>OK</sub>	± 50	mA
DC Output Current	I <sub>OUT</sub>	± 50	mA
DC V <sub>cc</sub> /Ground Current	I <sub>cc</sub>	± 100	mA
Power Dissipation	P <sub>D</sub>	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T <sub>stg</sub>	<b>−65~150</b>	°C

<sup>\*500</sup>mW in the range of Ta =  $-40^{\circ}$ C ~65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C should be applied up to 300mW.

## **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2.0~5.5	V
Input Voltage	V <sub>IN</sub>	0~V <sub>CC</sub>	V
Output Voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	<b>−40~85</b>	°C
Input Rise and Fall Time	dt/dV	$0 \sim 100 \text{ (Vcc} = 3.3 \pm 0.3 \text{V)} $ $0 \sim 20 \text{ (Vcc} = 5 \pm 0.5 \text{V)}$	ns / V

## DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V <sub>cc</sub>	Ta = 25°C			Ta = −40~85°C		UNIT
PARAIVIETER	STIVIBUL			(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level Input Voltage	V <sub>IH</sub>				1.50 2.10 3.85	 	_ _ _	1.50 2.10 3.85	_ _ _	V
Low - Level Input Voltage	V <sub>IL</sub>			2.0 3.0 5.5	_ _ _		0.50 0.90 1.65		0.50 0.90 1.65	٧
High - Level	V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -50 \mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	  -  -	1.9 2.9 4.4	  -  -	V
Oŭtput Voltage	V <sub>OH</sub>		$I_{OH} = -4mA$ $I_{OH} = -24mA$ $I_{OH} = -75mA*$	3.0 4.5 5.5	2.58 3.94 —			2.48 3.80 3.85		
Low - Level		V <sub>1 N</sub> =	$I_{OL} = 50 \mu A$	2.0 3.0 4.5	  -  -	0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	V
Output Voltage		V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 12 \text{mA}$ $I_{OL} = 24 \text{mA}$ $I_{OL} = 75 \text{mA*}$	3.0 4.5 5.5		111	0.36 0.36 —	_ _ _	0.44 0.44 1.65	V
3 - State Output Off - State Current	l <sub>oz</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	± 0.5	_	± 5.0	
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_	_	± 0.1	_	± 1.0	$\mu$ A
Quiescent Supply Current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GN	5.5	_	_	8.0	_	80.0		

<sup>\* :</sup> This spec indicates the capability of driving  $50\Omega$  transmission lines. One output should be tested at a time for a 10ms maximum duration.

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AC ELECTRICAL CHARACTERISTICS (  $C_L = 50 pF \;,\; R_L = 500 \Omega$  , Input  $\; t_r = t_f = 3 ns$  )

PARAMETER	SYMBOL	TEST CONDIT	TION	Ta = 25°0		:	$Ta = -40 \sim 85^{\circ}C$		UNIT
FARAIVIETER	STIVIBOL		V <sub>cc</sub> (V)	MIN.	TYP.	MAX.	MIN.	MAX.	CIVIT
Propagation Delay Time (A, B $-$ Y, $\overline{Y}$ )	t <sub>pLH</sub> t <sub>pHL</sub>		3.3 ± 0.3 5.0 ± 0.5	1 1	7.0 4.7	14.3 7.5	1.0 1.0	16.3 8.5	
Propagation Delay Time (SELECT $-Y, \overline{Y}$ )	t <sub>pLH</sub> t <sub>pHL</sub>		3.3 ± 0.3 5.0 ± 0.5	1 1	8.6 5.5	17.2 9.1	1.0 1.0	19.6 10.4	ns
Output Enable Time	t <sub>pZL</sub> t <sub>pHZ</sub>		3.3 ± 0.3 5.0 ± 0.5	_	7.3 5.0	14.0 7.9	1.0 1.0	16.0 9.0	
Output Disable Time	t <sub>pLZ</sub> t <sub>pHZ</sub>		3.3 ± 0.3 5.0 ± 0.5	_	5.6 5.1	9.6 7.9	1.0 1.0	11.0 9.0	
Input Capacitance	C <sub>IN</sub>			_	5	10	_	10	
Output Capacitance	C <sub>OUT</sub>		·	_	10	_	_	_	pF
Power Dissipation Capacitance	C <sub>PD</sub> (1)			_	28	_	_	_	

Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

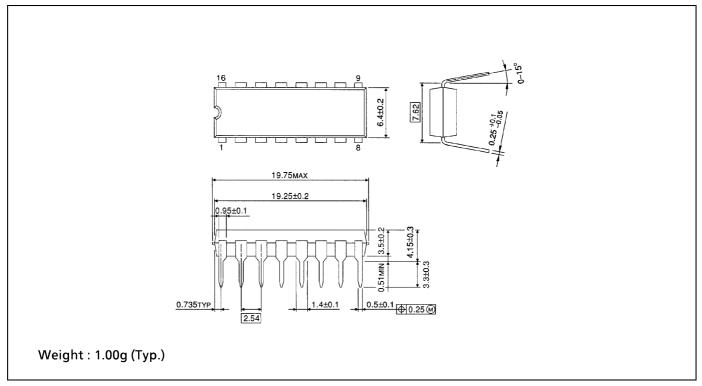
Average operating current can be obtained by the equation:

$$I_{CC}$$
(opr.) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$  (per bit)

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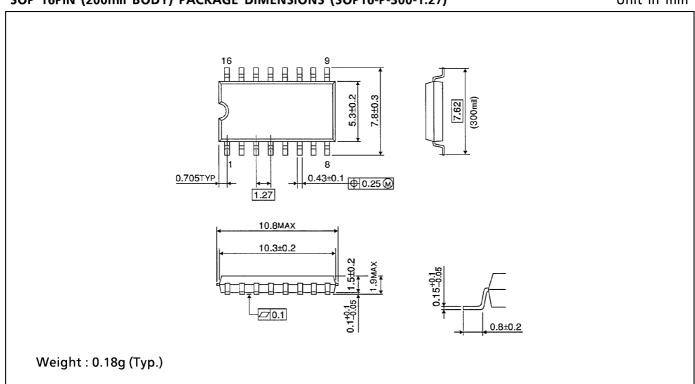
## DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

Unit in mm



## SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm

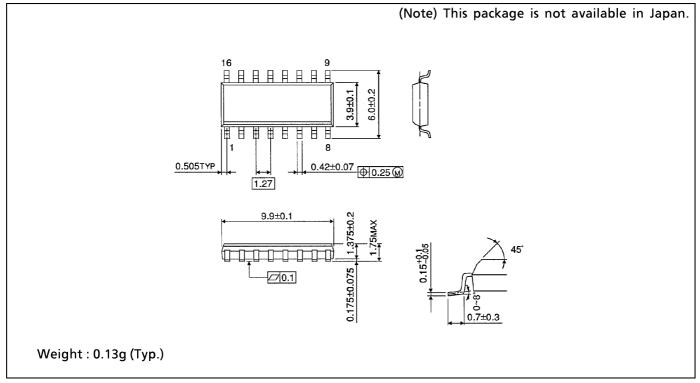


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## SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150 -1.27)

Unit in mm



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